# NSN 5961-01-369-9102

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#### Inclosure Material:

Metal

#### **Overall Length:**

Between 6.4 millimeters and 11.4 millimeters

#### **Overall Diameter:**

22.2 millimeters

## **Mounting Facility Quantity:**

2

#### Internal Configuration:

Field effect

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-204aa

# Electrode Internally-electrically Connected To Case:

Drain

## **Mounting Method:**

# Unthreaded hole

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

-120.0 drain to source voltage and -120.0 drain to gate voltage

## **Current Rating Per Characteristic:**

5.00 amperes drain current

## Power Rating Per Characteristic:

75.0 watts total power dissipation

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

## **Terminal Type And Quantity:**

2 uninsulated wire lead

Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

No

Fiig:

A110a0